RCA3054, RCA3055 File Number **618**

Silicon N-P-N VERSAWATT Transistors

Designed for Medium-Power Linear and Switching Service in Consumer, Automotive, and Industrial Applications

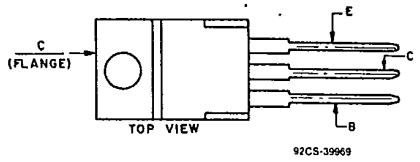
Features:

- Maximum safe-area-of-operation curves
- Low saturation voltages
- High dissipation ratings

Applications:

- Series and shunt regulators
- High-fidelity amplifiers
- Power-switching circuits

TERMINAL DESIGNATIONS



JEDEC TO-220AB

RCA3054 and RCA3055 are silicon n-p-n transistors intended for a wide variety of high-current applications. The construction of these devices renders them highly resistant to second breakdown over a wide range of operating conditions.

The VERSAWATT case has a proven thermal-cycle capability. This capability is assured by real-time quality controls in our manufacturing locations. The RCA3054 and RCA3055 are supplied in the JEDEC TO-220AB straight-lead version of the package. They are also available on special order in a variety of lead-form configurations.

MAXIMUM RATINGS, *Absolute-Maximum Values:*

		RCA3054	RCA3055	
COLLECTOR-TO-BASE VOLTAGE	V_{CBO}	90	100	V
COLLECTOR-TO-EMITTER SUSTAINING VOLTAGE:				
With external base-to-emitter resistance (R_{BE}) = 100 Ω	$V_{CER(sus)}$	60	70	V
With base open	$V_{CEO(sus)}$	55	60	V
With base reverse-biased V_{BE} = −1.5 V	$V_{CEV(sus)}$	90	90	V
EMITTER-TO-BASE VOLTAGE	V_{EBO}	7	7	V
CONTINUOUS COLLECTOR CURRENT	I_C	4	15	A
CONTINUOUS BASE CURRENT	I_B	2	4	A
TRANSISTOR DISSIPATION:	P_T			
At case temperatures up to 25°C		36	75	W
At case temperatures above 25°C		See Fig.3		
TEMPERATURE RANGE:				
Storage and Operating (Junction)		−65 to +150		°C
PIN TEMPERATURE (During Soldering):				
At distances ≥ 1/32 in. (0.8 mm) from seating plane for 10 s max.		235		°C

RCA3054, RCA3055

ELECTRICAL CHARACTERISTICS, *At Case Temperature (T_C) = 25°C unless otherwise specified*

CHARACTERISTIC	SYMBOL	TEST CONDITIONS					LIMITS				UNITS
		VOLTAGE V dc			CURRENT A dc		RCA3054		RCA3055		
		V_{CE}	V_{EB}	V_{BE}	I_C	I_B	MIN.	MAX.	MIN.	MAX.	
Collector-Cutoff Current: With base open	I_{CEO}	30				0	–	0.5	–	0.7	mA
With base-emitter junction reverse-biased	I_{CEX}	90 100		−1.5 −1.5			– –	1 –	– –	– 5	
At T_C = 150°C	I_{CEX}	90 100		−1.5 −1.5			– –	6 –	– –	– 30	
Emitter-Cutoff Current	I_{EBO}		7		0		–	1.0	–	5	mA
Collector-to-Emitter Sustaining Voltage: With base open	$V_{CEO(sus)}$				0.1[a] 0.2[a]	0 0	55 –	– –	– 60	– –	V
With external base-to-emitter resistance (R_{BE}) = 100 Ω	$V_{CER(sus)}$				0.1[a] 0.2[a]		60 –	– –	– 70	– –	
With base-emitter junction reverse-biased	$V_{CEV(sus)}$			−1.5	0.1[a]		90	–	90	–	
DC Forward-Current Transfer Ratio	h_{FE}	4 4 4 4			3[a] 10[a] 0.5[a] 4[a]		5 – 25 –	– – 100 –	– 5 – 20	– – – 70	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$				0.5[a] 4[a]	0.05[a] 0.4[a]	– –	1.0 –	– –	– 1.1	V
Base-to-Emitter Voltage	V_{BE}	4 4			0.5[a] 4[a]		– –	1.7 –	– –	– 1.8	V
Common-Emitter, Small-Signal, Short-Circuit, Forward Current Transfer Ratio Cutoff Frequency	f_{hfe}	4 4			0.1 1		30 –	– –	– 10	– –	kHz
Magnitude of Common-Emitter, Small-Signal Short-Circuit Forward Current Transfer Ratio (f = 0.4 MHz)	$\lvert h_{fe} \rvert$	4 4			0.1 1		2 –	– –	– 8	– –	
Common-Emitter, Small-Signal, Short-Circuit Forward Current Transfer Ratio (f = 1 kHz)	h_{fe}	4 4			0.1 1		25 –	– –	– 15	– 120	
Forward-Bias Second Breakdown Collector Current[b] (t ≥ 1 s)	$I_{S/b}$	55 60					0.65 –	– –	– 1.2	– –	A
Thermal Resistance: Junction-to-Case	$R\theta_{JC}$						–	3.5	–	1.67	°C/W
Junction-to-Ambient	$R\theta_{JA}$						–	70	–	70	

[a] Pulsed: Pulse duration = 300 μs, duty factor = 1.8%.
[b] Pulsed: 1-second non-repetitive pulse.

RCA3054, RCA3055

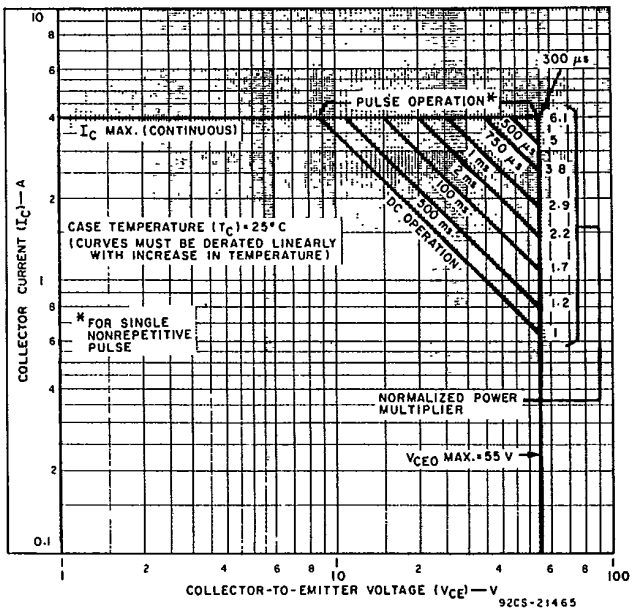


Fig. 1 — Maximum operating areas for RCA3054.

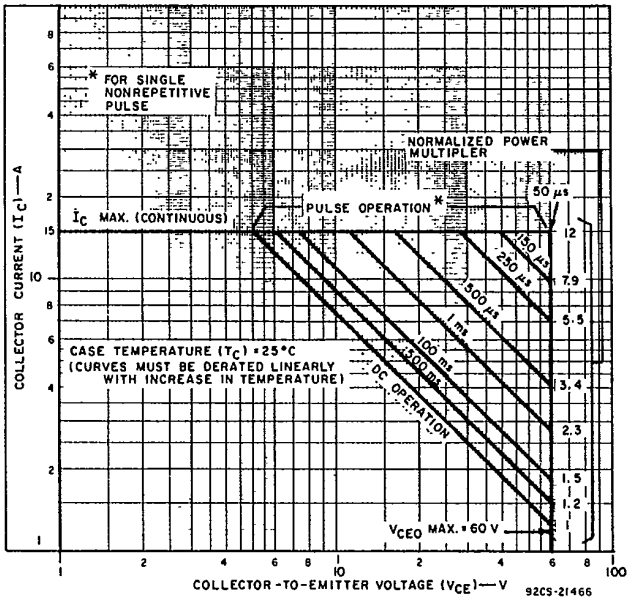


Fig. 2 — Maximum operating areas for RCA3055.

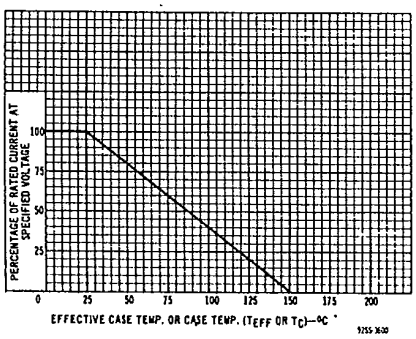


Fig. 3 — Derating curve for both types.

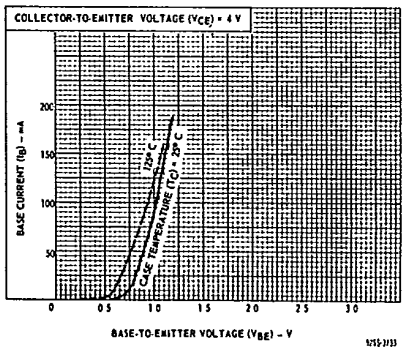


Fig. 4 — Typical input characteristics for RCA3054.

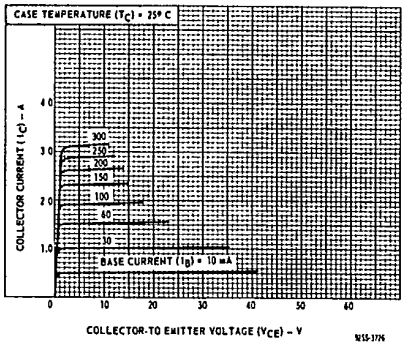


Fig. 5 — Typical output characteristics for RCA3054.

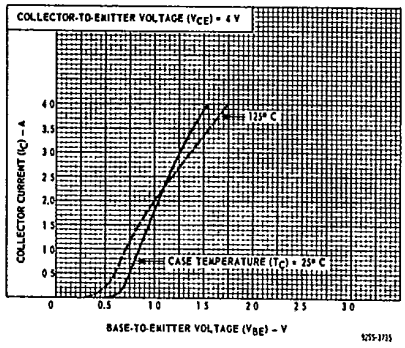


Fig. 6 — Typical transfer characteristics for RCA3054.

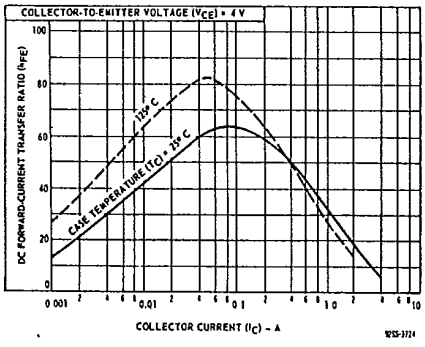


Fig. 7 — Typical dc beta characteristics for RCA3054.

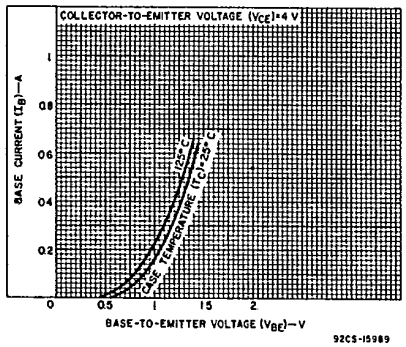


Fig. 8 — Typical input characteristics for RCA3055.

RCA3054, RCA3055

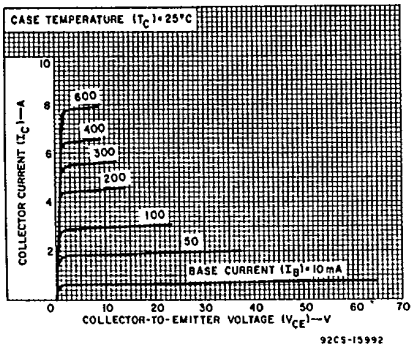


Fig. 9 — Typical output characteristics for RCA3055.

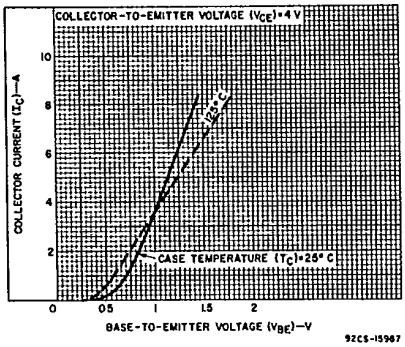


Fig. 10 — Typical transfer characteristics for RCA3055.

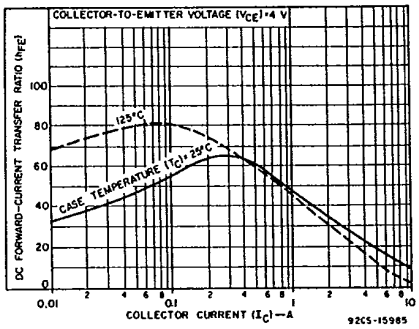


Fig. 11 — Typical dc beta characteristics for RCA3055.